

2SA1575/2SC4080

High-Frequency Amplifier, Wide-Band Amplifier Applications

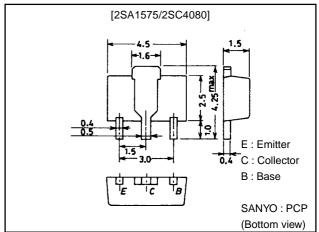
Features

- · High f_T.
- · High breakdown voltage.
- \cdot Small reverse transfer capacitance and excellent high-frequency characteristic.
- · Adoption of FBET process.

Package Dimensions

unit:mm

2038



(): 2SA1575

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		(-)200	V
Collector-to-Emitter Voltage	VCEO		(-)200	V
Emitter-to-Base Voltage	V _{EBO}		(-)4	V
Collector Current	IС		(-)100	mA
Collector Current (Pulse)	I _{CP}		(-)200	mA
Collector Dissipation	PC		500	mW
		Mounted on ceramic board (250mm²×0.8mm)	1.3	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Linit
			min	typ	max	Unit
Collector Cutoff Current	I _{CBO}	V _{CB} =(-)150V, I _E =0			(–)0.1	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB} =(-)2V, I _C =0			(–)1.0	μΑ
DC Current Gain	h _{FE} 1	V _{CE} =(-)10V, I _C =(-)10mA	40*		320*	
	h _{FE} 2	V _{CE} =(-)10V, I _C =(-)60mA	20			
Gain-Bandwidth Product	f _T	V _{CE} =(-)30V, I _C =(-)30mA		400		MHz
Output Capacitance	C _{ob}	V _{CB} =(-)30V, f=1MHz		1.8		pF
				(2.3)		pF
Reverse Transfer Capacitance	C _{re}	V _{CB} =(-)30V, f=1MHz		1.4		pF
				(1.7)		pF
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =(-)20mA, I _B =(-)2mA			(–)1.0	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =(-)20mA, I _B =(-)2mA			(–)1.0	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =(-)10μΑ, I _E =0	(-)200			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =(−)1mA, R _{BE} =∞	(-)200			V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E =(-)100μA, I _C =0	(-)4			V

 Marking 2SA1575 : AF 2SC4080 : CI h_{FE} rank : C, D, E, F

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